



### **NPN Switching Transistor**

#### > Features

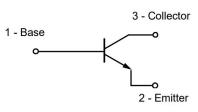
VCB	VCE	VEB	IC
50V	45V	5V	100mA

# Pin configuration



### > Description

The NPN Transistor is designed for use in linear and switching applications. The device is housed in the SOT-323 package, which is designed for telephony and professional communication equipment.



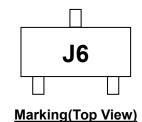
#### Circuit Diagram

## Applications

- General purpose switching and amplification
- Telephony and professional communication equipment

### > Ordering Information

Device	Package	Shipping
SSCN9014GS7	SOT-323	3000/Reel





## > Absolute Maximum Ratings( $T_A=25^{\circ}C$ unless otherwise noted)

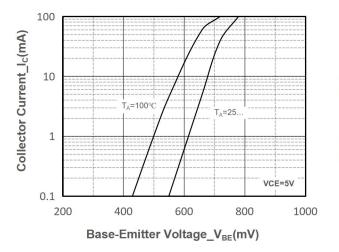
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector- Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current-Continuous	lc	100	mA
Collector Power Dissipation	Pc	200	mW
Junction Temperature	TJ	625	°C
Storage Temperature	T <sub>STG</sub>	-55 to 150	°C

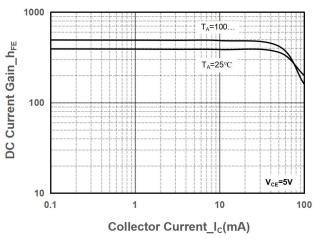
## > Electrical Characteristics ( $T_A=25^{\circ}C$ unless otherwise noted)

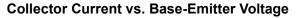
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	I <sub>C</sub> =100uA, I <sub>E</sub> =0	50			V
Collector-emitter Breakdown Voltage	BV <sub>CEO</sub>	I <sub>C</sub> =0.1mA, I <sub>B</sub> =0	45			V
Emitter -Base Breakdown Voltage	BV <sub>EBO</sub>	I <sub>E</sub> =100uA, I <sub>C</sub> =0	5			V
Collector Cutoff Current	I <sub>СВО</sub>	V <sub>CB</sub> =50V, I <sub>E</sub> =0			0.1	μA
Collector Cutoff Current	I <sub>CEO</sub>	V <sub>CE</sub> =35V, I <sub>B</sub> =0			1	μA
Emitter Cutoff Current	Іево	V <sub>EB</sub> =3V, I <sub>C</sub> =0			0.1	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =1mA	200		1000	
Collector-Emitter Saturation Voltage	V <sub>CE (sat)</sub>	Ic=100mA, I <sub>B</sub> =5mA			0.3	V
Base-Emitter Saturation Voltage	V <sub>BE (sat)</sub>	Ic=100mA, I <sub>B</sub> =5mA			1	V
Transition frequency	f⊤	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA f=30MHz	150			MHz

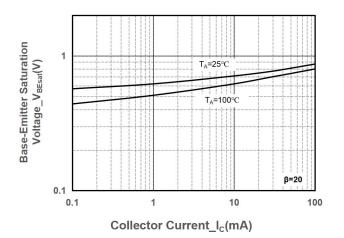


# > Typical Performance Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

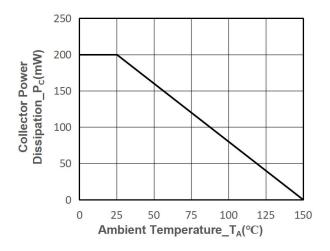






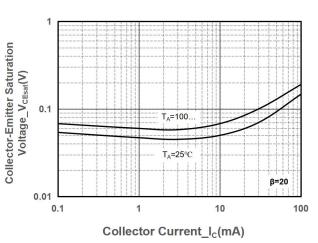




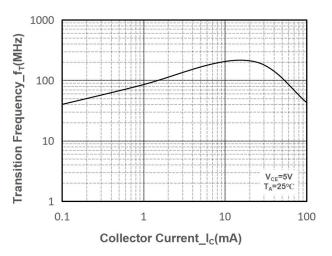




DC Current Gain vs. Collector Current



V<sub>CE(sat)</sub> vs. Collector Current

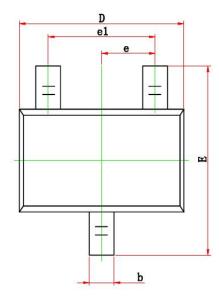


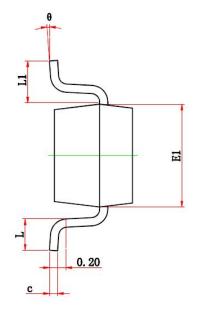
#### **Transition Frequency vs. Collector Current**

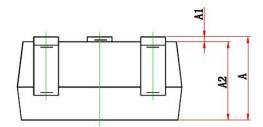


> Package Information

<u>SOT-323</u>







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	2.150	2.450	0.085	0.096	
E1	1.150	1.350	0.045	0.053	
e	0.650 TYP.		0.026 TYP.		
e1	1.200	1.400	0.047	0.055	
L	0.260	0.460	0.010	0.018	
L1	0.525 REF.		0.021 REF.		
θ	0°	8°	0°	8°	



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